

Quantum spin Hall effect in two-dimensional transition

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Citation Report

#	ARTICLE	IF	CITATIONS
1	Phase-engineered transition-metal dichalcogenides for energy and electronics. MRS Bulletin, 2015, 40, 585-591.	1.7	71
2	Synthesis and structure of two-dimensional transition-metal dichalcogenides. MRS Bulletin, 2015, 40, 566-576.	1.7	43
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6	Holographic treatment of boundary disorder in a topological insulator. Physical Review B, 2015, 92, .	1.1	6
7	Zero-field and time-reversal-symmetry-broken topological phase transitions in graphene. Physical Review B, 2015, 92, .	1.1	15
8	Large-gap two-dimensional topological insulator in oxygen functionalized MXene. Physical Review B, 2015, 92, .	1.1	229
9	Large-gap quantum spin Hall states in decorated stanene grown on a substrate. Physical Review B, 2015, 92, .	1.1	108
10	Quantum spin Hall effect and topological phase transition in two-dimensional square transition-metal dichalcogenides. Physical Review B, 2015, 92, .	1.1	117
11	Combined fast reversible liquidlike elastic deformation with topological phase transition in Na_3Bi quantum spin Hall insulators in square lattice. Physical Review B, 2015, 92, .	1.1	9

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